

### Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

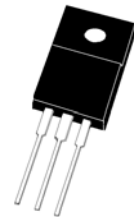
Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical application are in switching Mode Power Supplies such as adaptators, DC/DC convertes, free-wheeling and polarity protection diodes.

**SCHOTTKY BARRIER  
RECTIFIERS**

**20 AMPERES  
120 VOLTS**

#### Features

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 175°C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O



**ITO-220AB**

\* *In compliance with EU RoHs 2002/95/EC directives*

#### MAXIMUM RATINGS

Characteristic	Symbol	MBRF20120C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	120	V
RMS Reverse Voltage	$V_{R(RMS)}$	84	V
Average Rectifier Forward Current ( per diode ) Total Device (Rated $V_R$ ), $T_C=125^\circ\text{C}$	$I_{F(AV)}$	10 20	A
Peak Repetitive Forward Current (Rate $V_R$ , Square Wave, 20kHz)	$I_{FM}$	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	$I_{FSM}$	150	A
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-65 to +175	°C

#### THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta j-c}$	4.0	°C/w
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#### ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	MBRF20120C	Unit
Maximum Instantaneous Forward Voltage ( per diode ) ( $I_F=10$ Amp $T_C=25^\circ\text{C}$ ) ( $I_F=10$ Amp $T_C=125^\circ\text{C}$ )	$V_F$	0.85 0.78	V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C=25^\circ\text{C}$ ) ( Rated DC Voltage, $T_C=125^\circ\text{C}$ )	$I_R$	0.01 10	mA

FIG-1 FORWARD CURRENT DERATING CURVE

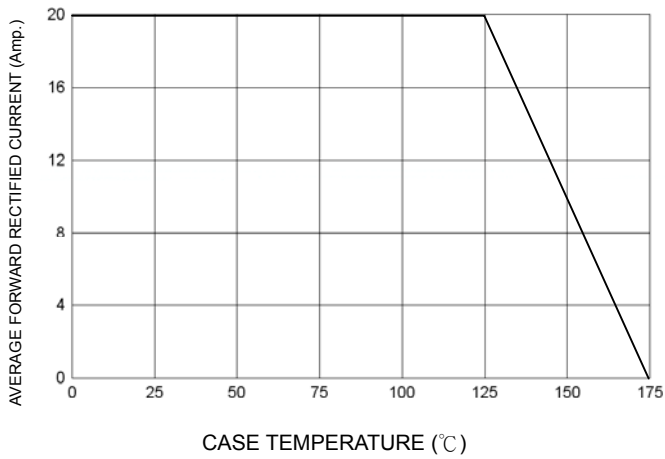


FIG-2 TYPICAL FORWARD CHARACTERISTICS

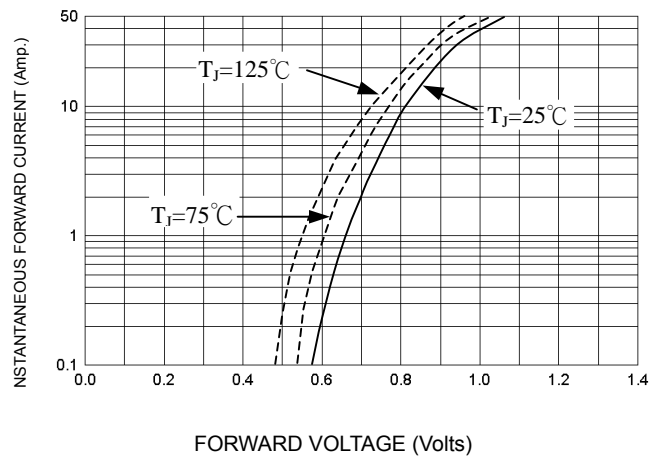


FIG-3 TYPICAL REVERSE CHARACTERISTICS

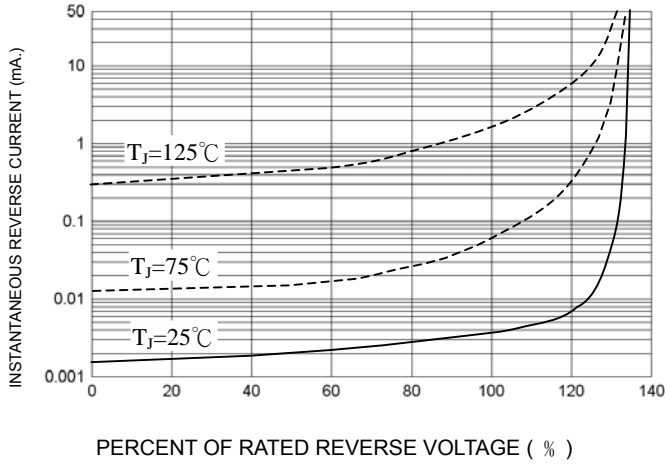


FIG-4 TYPICAL JUNCTION CAPACITANCE

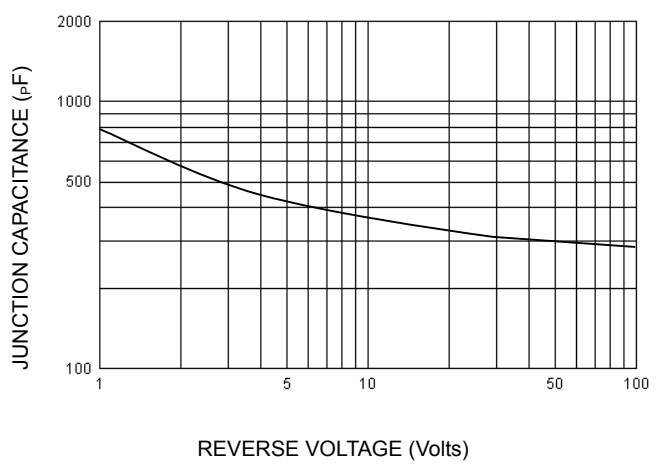


FIG-5 PEAK FORWARD SURGE CURRENT

